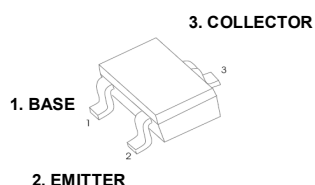
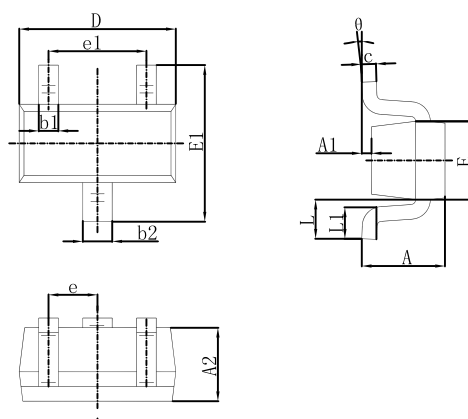


FEATURES

- Complementary to MMBT3906T
- Small Package



SOT-523



Symbol	Dimensions in Millimeters		Dimensions in Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.900	0.028	0.035
A1	0.000	0.100	0.000	0.004
A2	0.700	0.800	0.028	0.031
b1	0.150	0.250	0.006	0.010
b2	0.250	0.350	0.010	0.014
c	0.100	0.200	0.004	0.008
D	1.500	1.700	0.059	0.067
E	0.700	0.900	0.028	0.035
E1	1.450	1.750	0.057	0.069
e	0.500 TYP.		0.020 TYP.	
e1	0.900	1.100	0.035	0.043
L	0.400 REF.		0.016 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

Dimensions in inches and (millimeters)

MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	40	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current	200	mA
P_C	Collector Power Dissipation	150	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	833	$^{\circ}\text{C}/\text{W}$
T_j	Junction Temperature	150	$^{\circ}\text{C}$
T_{stg}	Storage Temperature	-55~+150	$^{\circ}\text{C}$

MMBT3904T

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=10\mu\text{A}$, $I_E=0$	60			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}$, $I_B=0$	40			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=10\mu\text{A}$, $I_C=0$	6			V
Collector cut-off current	I_{CEX}	$V_{CE}=30\text{V}$, $V_{EB(off)}=3\text{V}$			50	nA
Emitter cut-off current	I_{EBO}	$V_{EB}=5\text{V}$, $I_C=0$			100	nA
DC current gain	$h_{FE(1)}$	$V_{CE}=1\text{V}$, $I_C=1\text{mA}$	70			
	$h_{FE(2)}$	$V_{CE}=1\text{V}$, $I_C=10\text{mA}$	100		300	
	$h_{FE(3)}$	$V_{CE}=1\text{V}$, $I_C=50\text{mA}$	60			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=10\text{mA}$, $I_B=1\text{mA}$			0.2	V
		$I_C=50\text{mA}$, $I_B=5\text{mA}$			0.3	V
Collector-emitter saturation voltage	$V_{BE(sat)}$	$I_C=10\text{mA}$, $I_B=1\text{mA}$	0.65		0.85	V
		$I_C=50\text{mA}$, $I_B=5\text{mA}$			0.95	V
Transition frequency	f_T	$V_{CE}=20\text{V}$, $I_C=10\text{mA}$, $f=100\text{MHz}$	300			MHz
Collector output capacitance	C_{ob}	$V_{CB}=5\text{V}$, $I_E=0$, $f=1\text{MHz}$			4	pF
Base input capacitance	C_{ib}	$V_{EB}=0.5\text{V}$, $I_C=0$, $f=1\text{MHz}$			8	pF
Delay time	t_d	$V_{CC}=3\text{V}$, $V_{BE(off)}=-0.5\text{V}$, $I_C=10\text{mA}$, $I_{B1}=1\text{mA}$			35	ns
Rise time	t_r	$V_{CC}=3\text{V}$, $V_{BE(off)}=-0.5\text{V}$, $I_C=10\text{mA}$, $I_{B1}=1\text{mA}$			35	ns
Storage time	t_s	$V_{CC}=3\text{V}$, $I_C=10\text{mA}$, $I_{B1}=I_{B2}=1\text{mA}$			200	ns
Fall time	t_f	$V_{CC}=3\text{V}$, $I_C=10\text{mA}$, $I_{B1}=I_{B2}=1\text{mA}$			50	ns

RATING AND CHARACTERISTIC CURVES (MMBT3904T)

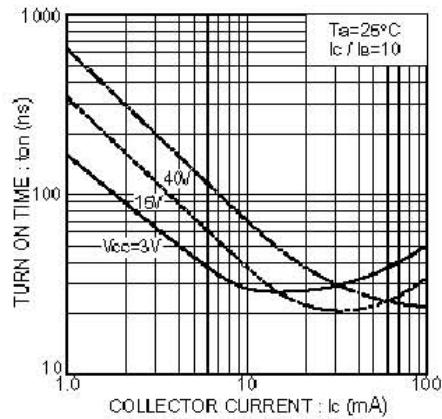


Fig.5 Turn-on time vs. collector current

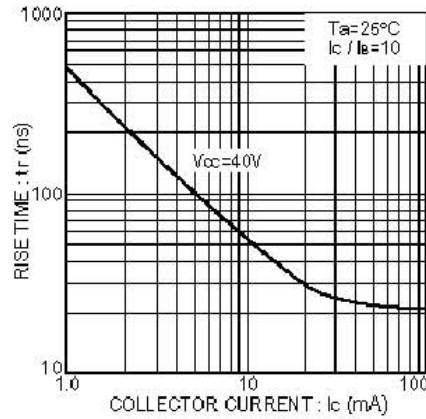


Fig.6 Rise time vs. collector current

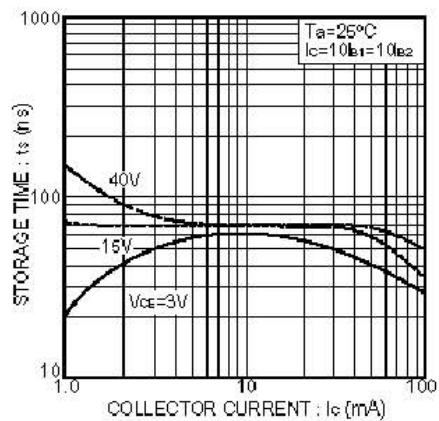


Fig.7 Storage time vs. collector current

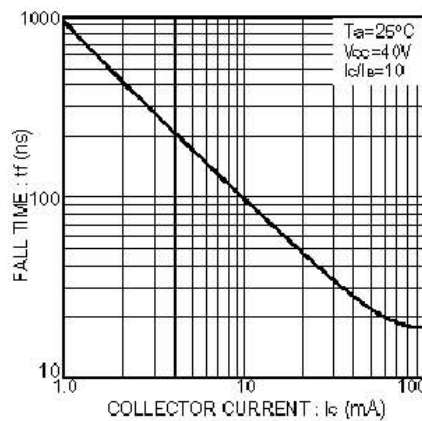


Fig.8 Fall time vs. collector current

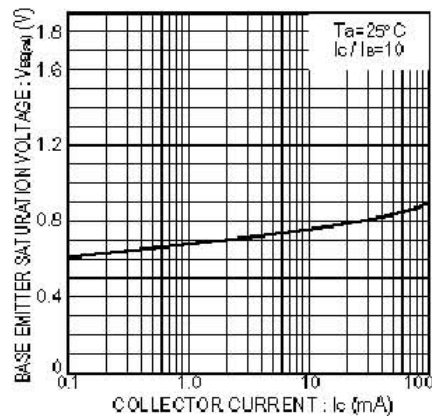


Fig.9 Base-emitter saturation voltage vs. collector current

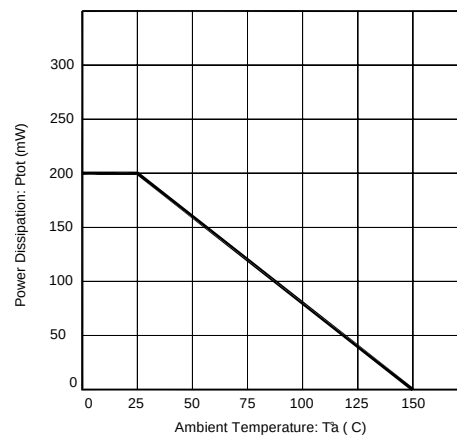


Fig.10 Power Dissipation vs Ambient Temperature